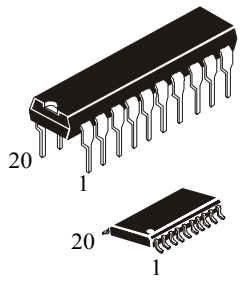
IN74LV574

Octal D-type flip-flop; positive edge-trigger (3-State)



ORDERING INFORMATION

IN74LV574N	Plastic DIP
IN74LV574DW	SOIC

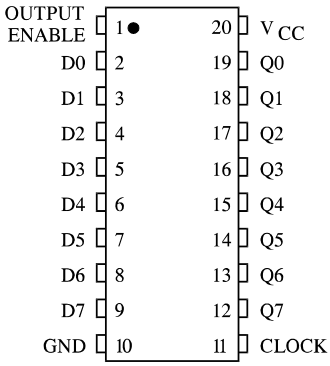
T_A = -40° to 125° C for all packages

The 74LV574 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT574.

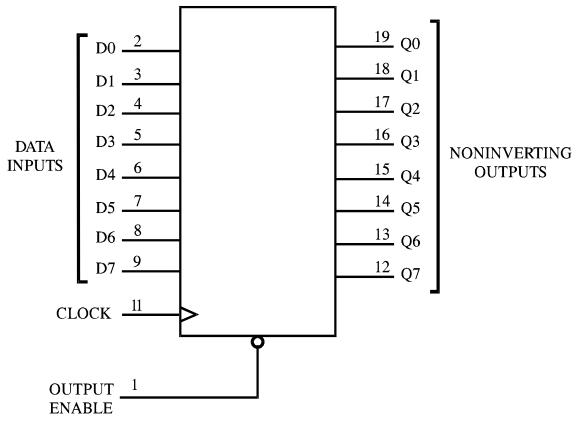
The 74LV574 is an octal D-type flip–flop featuring separate D-type inputs for each flip-flop and non-inverting 3-state outputs for oriented applications. A clock (CP) and an output enable (OE) input are common to all flip-flops. The eight flip-flops will store the state of their individual D-inputs that meet the set-up and hold times requirements on the LOW-to-HIGH CP transition. When OE is LOW, the contents of the eight flip-flops are available at the outputs. When OE is HIGH, the outputs go to the high impedance OFF-state. Operation of the OE input does not affect the state of the flip-flops.

- Output voltage levels are compatible with input levels of CMOS, NMOS and TTL IC_S
- Supply voltage range: 1.0 to 5.5 V
- Low input current: 1.0 μA; 0.1 μA at T = 25 °C
- High Noise Immunity Characteristic of CMOS Devices

PIN ASSIGNMENT



LOGIC DIAGRAM



PIN 20=V_{CC}
PIN 10 = GND

FUNCTION TABLE

Inputs			Output
Output Enable	Clock	D	Q
L	↑	H	H
L	↑	L	L
L	L,H, ↓	X	no change
H	X	X	Z

H= high level
L = low level
X = don't care
Z = high impedance

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	DC supply voltage	-0.5 to +7.0	V
I_{IK} *1	Input diode current	±20	mA
I_{OK} *2	Output diode current	±50	mA
I_O *3	Output source or sink current	±35	mA
I_{CC}	V_{CC} current	±70	mA
I_{GND}	GND current	±70	mA
P_D	Power dissipation per package: Plastic DIP *4 SO *4	 750 500	mW
Tstg	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature, 1.5 mm (Plastic DIP Package), 0.3 mm (SO Package) from Case for 4 Seconds	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur.
Functional operation should be restricted to the Recommended Operating Conditions.
*1 $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V.
*2 $V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V.
*3 -0.5 V $< V_O < V_{CC} + 0.5$ V.
*4 Derating - Plastic DIP: - 12 mW/°C from 70° to 125°C
SO Package: : - 8 mW/°C from 70° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	DC Supply Voltage		1.0	5.5	V
V_I	DC Input Voltage		0	V_{CC}	V
V_O	DC Output Voltage		0	V_{CC}	V
T_A	Operating Temperature, All Package Types		-40	+125	°C
t_r, t_f	Input Rise and Fall Time (Figure 1)	$0 V \le V_{CC} \le 2.0$ V $2.0 V \le V_{CC} \le 2.7$ V $2.7 V \le V_{CC} \le 3.6$ V $3.6 V \le V_{CC} \le 5.5$ V	0 0 0 0	500 200 100 50	ns

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range GND≤(V_{IN} or V_{OUT})≤V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

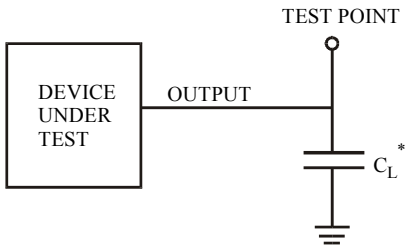
Symbol	Parameter	Test conditions	V_{CC} V	Guaranteed Limit								Unit
				25°C		-40°C		85°C		125°C		
				min	max	min	max	min	max	min	max	
V_{IH}	HIGH level input voltage		1.2 2.0 2.7 3.0 3.6 4.5 5.5	0.9 1.4 2.0 2.0 2.0 3.15 3.85	- - - - - - -	0.9 1.4 2.0 2.0 2.0 3.15 3.85	- - - - - - -	0.9 1.4 2.0 2.0 2.0 3.15 3.85	- - - - - - -	0.9 1.4 2.0 2.0 2.0 3.15 3.85	- - - - - - -	V
V_{IL}	LOW level output voltage		1.2 2.0 2.7 3.0 3.6 4.5 5.5	- - - - - - -	0.3 0.6 0.8 0.8 0.8 1.35 1.65	- - - - - - -	0.3 0.6 0.8 0.8 0.8 1.35 1.65	- - - - - - -	0.3 0.6 0.8 0.8 0.8 1.35 1.65	- - - - - - -	0.3 0.6 0.8 0.8 0.8 1.35 1.65	V
V_{OH}	HIGH level output voltage	$V_I = V_{IH}$ or V_{IL} I_O = -100 μA	1.2 2.0 2.7 3.0 3.6 4.5 5.5	1.05 1.85 2.55 2.85 3.45 4.35 5.35	- - - - - - -	1.05 1.85 2.55 2.85 3.45 4.35 5.35	- - - - - - -	1.0 1.8 2.5 2.8 3.4 4.3 5.3	- - - - - - -	1.0 1.8 2.5 2.8 3.4 4.3 5.3	- - - - - - -	V
		$V_I = V_{IH}$ or V_{IL} I_O = -8 mA	3.0	2.48	-	2.48	-	2.40	-	2.20	-	V
		$V_I = V_{IH}$ or V_{IL} I_O = -16 mA	4.5	3.70	-	3.70	-	3.60	-	3.50	-	V
V_{OL}	LOW level output voltage	$V_I = V_{IH}$ or V_{IL} I_O = 100 μA	1.2 2.0 2.7 3.0 3.6 4.5 5.5	- - - - - - -	0.15 0.15 0.15 0.15 0.15 0.15 0.15	- - - - - - -	0.15 0.15 0.15 0.15 0.15 0.15 0.15	- - - - - - -	0.2 0.2 0.2 0.2 0.2 0.2 0.2	- - - - - - -	0.2 0.2 0.2 0.2 0.2 0.2 0.2	V
		$V_I = V_{IH}$ or V_{IL} I_O = 8 mA	3.0	-	0.33	-	0.33	-	0.40	-	0.50	V
		$V_I = V_{IH}$ or V_{IL} I_O = 16 mA	4.5	-	0.40	-	0.40	-	0.55	-	0.65	V
I_I	Input current	$V_I = V_{CC}$ or 0 V	5.5	-	±0.1	-	±0.1	-	±1.0	-	±1.0	μA
I_{CC}	Supply current	$V_I = V_{CC}$ or 0 V I_O = 0 μA	5.5	-	8.0	-	8.0	-	20	-	160	μA

I_{CC1}	Additional supply current per input	$V_I = V_{CC} - 0.6V$	2.7 3.6	-	0.2	-	0.2	-	0.5		0.85	mA
I_{OZ}	Three state leakage current	3-state output V_I (11) = V_{IH} V_O =V_{CC} or 0 V	5.5	-	±0.5	-	±0.5	-	±5	-	±10	μA

AC ELECTRICAL CHARACTERISTICS (C_L=50 pF, t_r=t_f=2.5 ns)

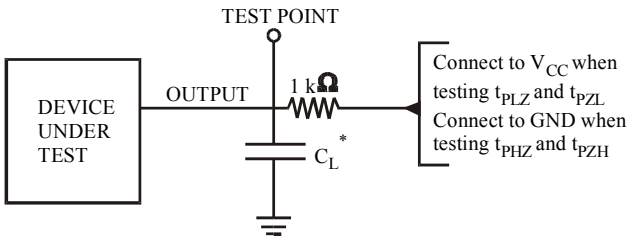
Symbol	Parameter	Test conditions	V_{CC} V	Guaranteed Limit						Unit
				-40°C to 25°C		85°C		125°C		
				min	max	min	max	min	max	
t_{PHL}, t_{PLH}	Propagation delay , Clock to Q	V_I = 0 V or V_I Figures 1,3	1.2 2.0 2.7 3.0 4.5	- - - - -	160 26 20 16 14	- - - - -	170 34 25 20 17	- - - - -	200 43 31 25 21	ns
t_{PHZ}, t_{PLZ}	Propagation delay, OE to Q	V_I = 0 V or V_I Figures 2,4	1.2 2.0 2.7 3.0 4.5	- - - - -	160 31 23 20 17	- - - - -	170 39 29 24 20	- - - - -	200 48 36 29 24	ns
t_{PZH}, t_{PZL}	Propagation delay, OE to Q	V_I = 0 V or V_I Figures 2,4	1.2 2.0 2.7 3.0 4.5	- - - - -	140 26 20 16 14	- - - - -	160 34 25 20 17	- - - - -	180 43 31 25 21	ns
C_I	Input capacitance		5.5	-	7.0*	-	-	-	-	pF
C_{PD}	Power dissipation capacitance (per flip-flop)	V_I = 0 V or V_{CC}	5.5	-	50*	-	-	-	-	pF

* T = 25°C



* Includes all probe and jig capacitance

Figure 1. Test Circuit

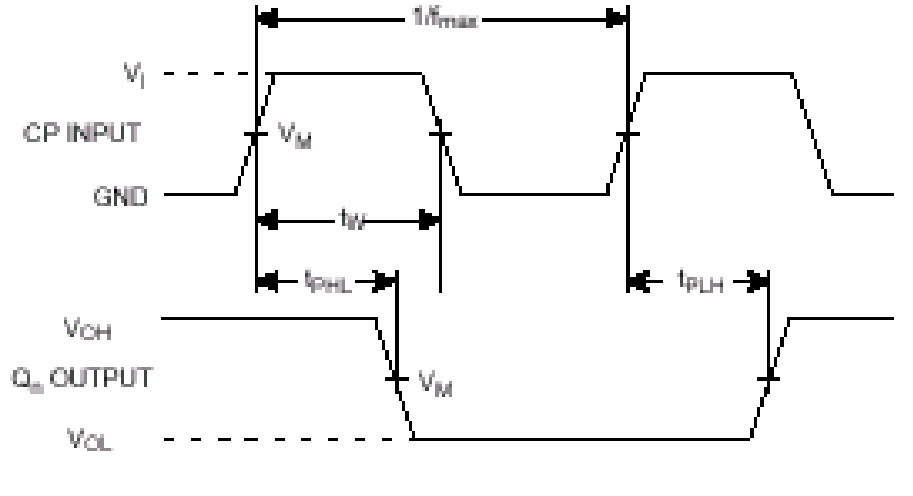


* Includes all probe and jig capacitance

Figure 2. Test Circuit

TIMING REQUIREMENTS (C_L=50 pF, t_r=t_f=2.5 ns)

Symbol	Parameter	Test conditions	V_{CC} V	Guaranteed Limit						Unit
				-40°C to 25°C		85°C		125°C		
				min	max	min	max	min	max	
t_w	Pulse Width, Clock (high)	V_I = 0 V or V_I Figures 1,3	1.2 2.0 2.7 3.0 4.5	120 29 21 17 15	- - - - -	 34 25 20	 - - -	 41 30 24	 - - -	ns
t_{su}	Setup Time, Data to Clock	V_I = 0 V or V_I Figures 1,5	1.2 2.0 2.7 3.0 4.5	40 19 14 11 9	- - - - -	 22 16 13	 - - -	 26 19 15	 - - -	ns
t_h	Hold Time, Clock to Data	V_I = 0 V or V_I Figures 1,5	1.2 2.0 2.7 3.0	5 5 5 5	- - - -	5 5 5 5	- - - -	5 5 5 5	- - - -	ns
f_c	Clock Frequency	V_I = 0 V or V_I Figures 1,3	1.2 2.0 2.7 3.0 4.5	- - - - -	2 17 21 27 31	 - - -	 15 19 24	 - - -	 12 16 20	MHz



V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

Figure 3. Switching Waveforms

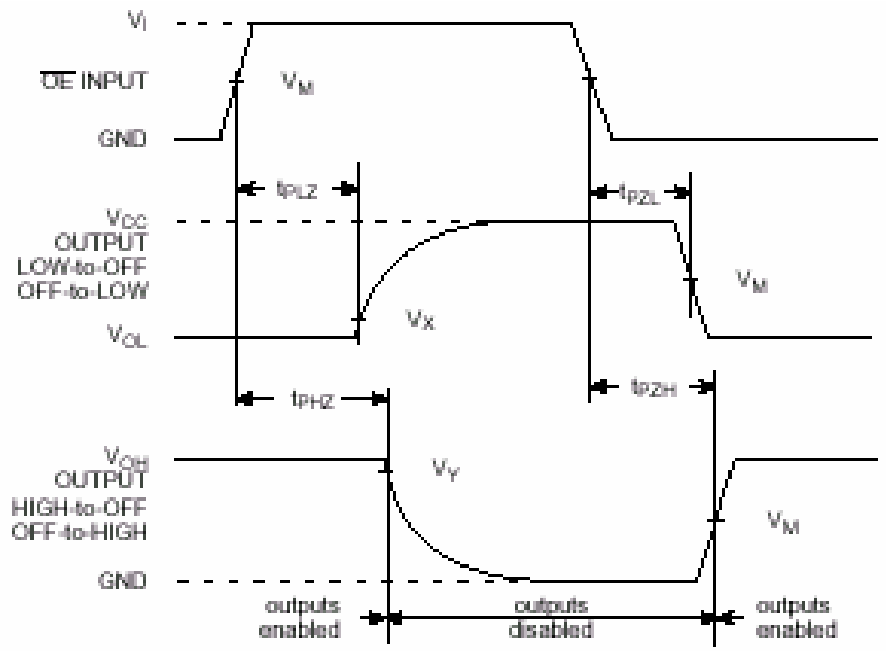


Figure 4. Switching Waveforms

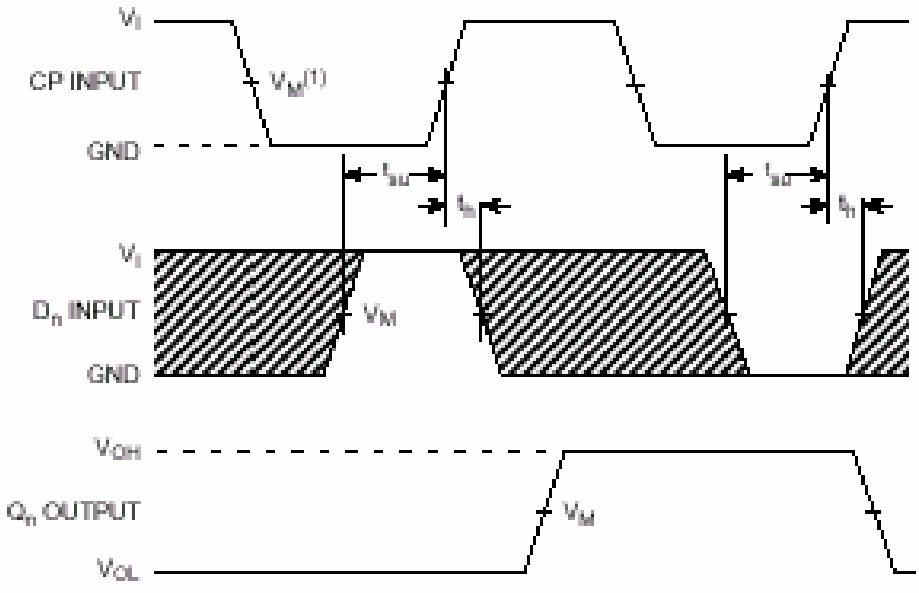
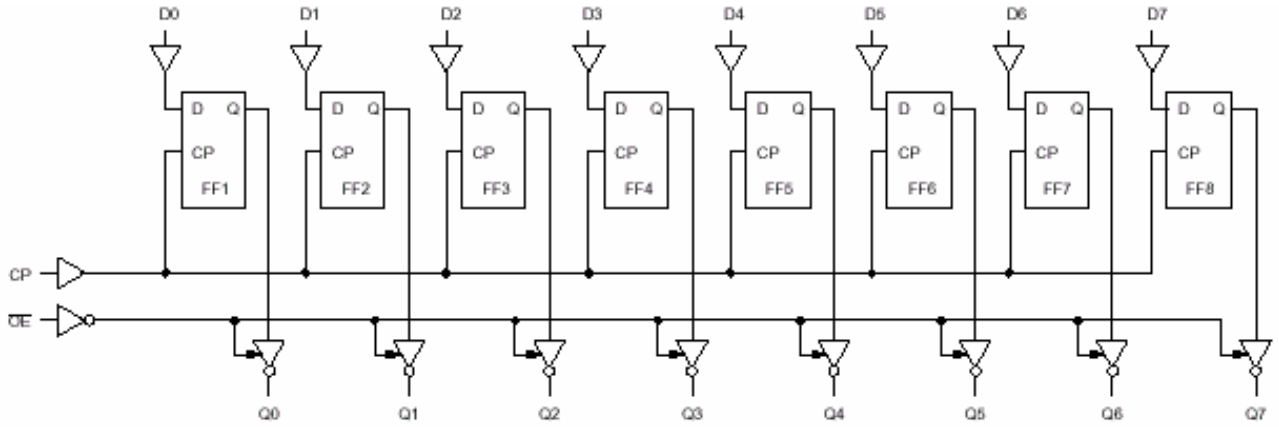


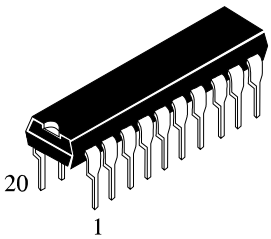
Figure 5. Switching Waveforms

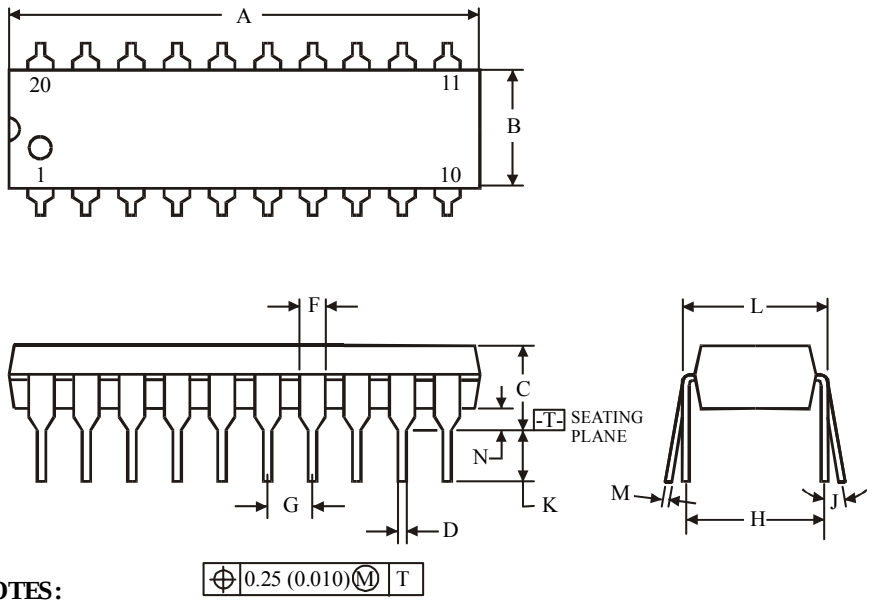
Symbol	V_{CC}, V	Temperature, °C					
		-40°C to 25		85		125	
		Level of a signal					
		V	%	V	%	V	%
V_I	1.2	1.2	-	1.2	-	1.2	-
	2.0	2.0	-	2.0	-	2.0	-
	2.7	2.7	-	2.7	-	2.7	-
	3.0	3.0	-	3.0	-	3.0	-
	4.5	4.5	-	4.5	-	4.5	-
V_M INPUTS	1.2	0.6	50	0.6	50	0.6	50
	2.0	1.0	50	1.0	50	1.0	50
	2.7	1.5	56	1.5	56	1.5	56
	3.0	1.5	56	1.5	56	1.5	56
	4.5	2.25	50	2.25	50	2.25	50
V_M OUTPUTS	1.2	0.6	50	0.6	50	0.6	50
	2.0	1.0	50	1.0	50	1.0	50
	2.7	1.5	58	1.5	60	1.5	62
	3.0	1.5	52	1.5	53	1.5	55
	4.5	2.25	50	2.25	50	2.25	50
V_X	1.2	0.32	12	0.37	12.5	0.37	12.5
	2.0	0.4	11	0.45	11	0.45	11
	2.7	0.55	12	0.6	12.5	0.65	12.7
	3.0	0.6	11	0.65	11	0.7	11.5
	4.5	0.85	12	0.90	12	1.0	11
V_Y	1.2	0.88	88	0.78	86.5	0.68	85
	2.0	1.5	88	1.4	87.5	1.3	86.5
	2.7	2.1	87.5	2.0	87	1.9	86
	3.0	2.3	88	2.2	88	2.1	87.5
	4.5	3.45	88	3.35	88	3.25	88

EXPANDED LOGIC DIAGRAM



N SUFFIX PLASTIC DIP
(MS - 001AD)





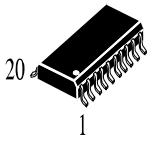
	Dimension, mm	
Symbol	**MIN**	**MAX**
A	24.89	26.92
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

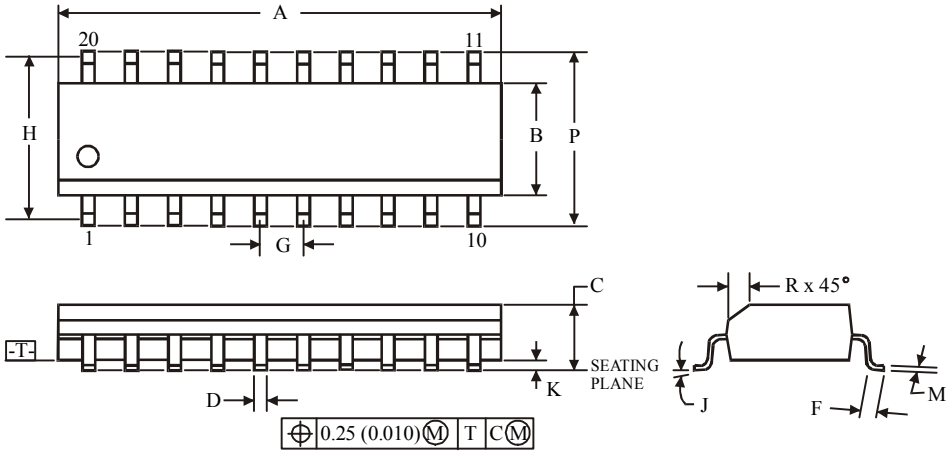
NOTES:

1. Dimensions “A”, “B” do not include mold flash or protrusions.

   Maximum mold flash or protrusions 0.25 mm (0.010) per side.

D SUFFIX SOIC
(MS - 013AC)





	Dimension, mm	
Symbol	**MIN**	**MAX**
A	12.6	13
B	7.4	7.6
C	2.35	2.65
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	9.53	
J	0°	8°
K	0.1	0.3
M	0.23	0.32
P	10	10.65
R	0.25	0.75

NOTES:

1. Dimensions A and B do not include mold flash or protrusion.
2. Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B – 0.25 mm (0.010) per side.